

View Online at <https://aerobasegroup.com/nsn/5961-01-168-3038>

Inclosure Material:

Plastic

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 85.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

100.00 microamperes zero-gate-voltage source current preset

Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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